NSN 5961-00-106-4309

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View Online at https://aerobasegroup.com/nsn/5961-00-106-4309 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.230 inches **Overall Height:** 0.230 inches **Overall Width:** 0.370 inches **Mounting Facility Quantity: Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 1.00 amperes collector current, dc **Power Rating Per Characteristic:** 10.0 watts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity: Specification Or Standard:** 2n4430 type Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli Fiig:

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